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[^0]
## FPF1207／FPF1208

## IntelliMAX ${ }^{\text {TM }}$ Advanced Load Switch

## Features

－ 1.2 V to 4.0 V Input Voltage Operating Range
－Typical Ron： $50 \mathrm{~m} \Omega$ at $\mathrm{V}_{\mathbb{I N}}=3.3 \mathrm{~V}$
$77 \mathrm{~m} \Omega$ at $\mathrm{V}_{\mathbb{I N}}=1.8 \mathrm{~V}$
$150 \mathrm{~m} \Omega$ at $\mathrm{V}_{\mathrm{IN}}=1.2 \mathrm{~V}$
－Slew Rate Control with $t_{\mathrm{R}}: 110 \mu \mathrm{~s}$
－Output Discharge Function on FPF1208
－Low $<1.5 \mu \mathrm{~A}$ Quiescent Current
－Extra Low $<100 n A$ Off Supply Current
－ESD Protected：Above 7000V HBM，2000V CDM
－GPIO／CMOS－Compatible Enable Circuitry
－4－Bump WLCSP $0.76 \mathrm{~mm} \times 0.76 \mathrm{~mm}, 0.4 \mathrm{~mm}$ Pitch

## Description

The FPF1207／08 is an ultra－small integrated IntelliMAX ${ }^{\text {TM }}$ load switch with integrated P －channel switch and analog control features．Integrated slew－rate control prevents inrush current and the resulting excessive voltage drop on power rail．The input voltage range operates from 1.2 V to 4.0 V to provide power－disconnect capability for post－regulated power rails in portable and consumer products．The low shut－off current of $1 \mu \mathrm{~A}$（maximum） allows power designs to meet standby and off－power drain specifications．

The FPF1207／08 is controlled by an active－HIGH logic input（ON pin）compatible with standard CMOS GPIO circuitry found on Field Programmable Gate Array （FPGA）and embedded processors．The FPF1207／08 is available in $0.76 \mathrm{~mm} \times 0.76 \mathrm{~mm} 4$－bump WLCSP．

## Applications

－Mobile Devices and Smart Phones
－Portable Media Devices
－Ultra－Portable／Mobile Computing
－Advanced Notebook，UMPC，MID
－Portable Medical Devices
－GPS and Navigation Equipment

## Ordering Information

| Part Number | Top <br> Marking | Switch <br> （Typical） <br> at 3．3V | Output <br> Discharge | ON Pin <br> Activity | $\mathbf{t}_{\boldsymbol{R}}$ | Package |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| FPF1207UCX | QG | $50 \mathrm{~m} \Omega$ | NA | Active <br> HIGH | $110 \mu \mathrm{~s}$ | 4－Ball，Wafer－Level Chip－ <br> Scale Package（WLCSP）， |
| FPF1208UCX | QH | $50 \mathrm{~m} \Omega$ | $65 \Omega$ | Active <br> HIGH | $110 \mu \mathrm{~s}$ | $0.76 \times 0.76 \mathrm{~mm}, 0.4 \mathrm{~mm}$ Pitch |

## Application Diagram



Figure 1. Typical Application

## Notes:

1. $\mathrm{C}_{\mathbb{N}}=1 \mu \mathrm{~F}, \mathrm{X} 5 \mathrm{R}, 0603$ (for example, Murata GRM185R60J105KE26).
2. $C_{\text {out }}=1 \mu \mathrm{~F}, \mathrm{X} 5 \mathrm{R}, 0805$ (for example, Murata GRM216R61A105KA01).

## Functional Block Diagram



Figure 2. Functional Block Diagram (Output Discharge for FPF1208 Only)

## Pin Configurations



Figure 3. WLCSP Bumps Facing Up (Top View)


Figure 5. Pin Assignments (Top View)

Pin 1


Figure 4. WLCSP Bumps Facing Down (Bottom View)


Figure 6. Pin Assignments (Bottom View)

## Pin Definitions

| Pin \# | Name | Description |
| :---: | :---: | :--- |
| A1 | Vout | Switch Output |
| A2 | VIN $_{\text {IN }}$ | Supply Input: Input to the power switch |
| B1 | GND | Ground |
| B2 | ON | ON/OFF control, active HIGH |

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Parameter |  | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| V IN | $\mathrm{V}_{\text {IN }}, \mathrm{V}_{\text {Out, }} \mathrm{V}_{\text {On }}$ to GND |  | -0.3 | 4.2 | V |
| Isw | Maximum Continuous Switch Current |  |  | 1.2 | A |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | 1.0 | W |
| $\mathrm{T}_{\text {STG }}$ | Storage Junction Temperature |  | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {A }}$ | Operating Temperature Range |  | -40 | +85 | ${ }^{\circ} \mathrm{C}$ |
| $\Theta_{J A}$ | Thermal Resistance, Junction-to-Ambient | 1S2P with One Thermal Via |  | 110 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  | 1S2P without Thermal Via |  | 95 |  |
| ESD | Electrostatic Discharge Capability ${ }^{(3,4)}$ | Human Body Model, JESD22-A114 | 7 |  | kV |
|  |  | Charged Device Model, JESD22-C101 | 2 |  |  |

## Notes:

3. Measured using 2S2P JEDEC std. PCB.
4. Measured using 2S2P JEDEC PCB COLD PLATE Method.

## Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

| Symbol | Parameter | Min. | Max. | Unit |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IN}}$ | Supply Voltage | 1.2 | 4.0 | V |
| $\mathrm{~T}_{\mathrm{A}}$ | Ambient Operating Temperature | -40 | +85 | ${ }^{\circ} \mathrm{C}$ |

## Electrical Characteristics

Unless otherwise noted, $\mathrm{V}_{\mathbb{I N}}=1.2$ to 4.0 V and $\mathrm{T}_{\mathrm{A}}=-40$ to $+85^{\circ} \mathrm{C}$. Typical values are at $\mathrm{V}_{\mathbb{I}}=3.3 \mathrm{~V}$ and $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Basic Operation |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN }}$ | Supply Voltage |  | 1.2 |  | 4.0 | V |
| $\mathrm{I}_{\text {Q(OFF) }}$ | Off Supply Current | $\mathrm{V}_{\text {ON }}=\mathrm{GND}, \mathrm{V}_{\text {OUT }}=$ Open, $\mathrm{V}_{\text {IN }}=4 \mathrm{~V}$ |  |  | 100 | nA |
| $\mathrm{I}_{\text {SD(OFF) }}$ | Off Switch Current | $\mathrm{V}_{\text {ON }}=\mathrm{GND}, \mathrm{V}_{\text {OUT }}=\mathrm{GND}$ |  |  | 1 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{Q}}$ | Quiescent Current | $\mathrm{l}_{\text {OUT }}=0 \mathrm{~mA}$ |  |  | 1.5 | $\mu \mathrm{A}$ |
| $\mathrm{R}_{\text {ON }}$ | On Resistance | $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$, $\mathrm{l}_{\text {OUT }}=200 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 50 | 66 | $m \Omega$ |
|  |  | $\mathrm{V}_{\text {IN }}=1.8 \mathrm{~V}$, $\mathrm{l}_{\text {OUT }}=200 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 77 | 91 |  |
|  |  | $\mathrm{V}_{\text {IN }}=1.2 \mathrm{~V}$, $\mathrm{l}_{\text {OUT }}=200 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 150 | 160 |  |
|  |  | $\mathrm{V}_{\text {IN }}=1.8 \mathrm{~V}$, $\mathrm{l}_{\text {OUT }}=200 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=85^{\circ} \mathrm{C}$ |  |  | 100 |  |
| $\mathrm{R}_{\text {PD }}$ | Output Discharge Rpull down | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{ON}}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{FORCE}}=20 \mathrm{~mA}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{FPF} 1208 \end{aligned}$ |  | 65 | 110 | $\Omega$ |
| $\mathrm{V}_{1 \text { H }}$ | On Input Logic HIGH Voltage | $\mathrm{V}_{\text {IN }}<1.5 \mathrm{~V}$ | 0.9 |  |  | V |
|  |  | $\mathrm{V}_{\mathrm{IN}}=1.5 \mathrm{~V}$ to 4.0 V | 1.1 |  |  |  |
| VIL | On Input Logic LOW Voltage | $\mathrm{V}_{\text {IN }}=1.2 \mathrm{~V}$ to 4.0V |  |  | 0.75 | V |
| lon | On Input Leakage | $\mathrm{V}_{\text {ON }}=\mathrm{V}_{\text {IN }}$ or GND |  |  | 1 | $\mu \mathrm{A}$ |
| Dynamic Characteristics ${ }^{(5)}$ |  |  |  |  |  |  |
| $\mathrm{t}_{\text {DON }}$ | Turn-On Delay ${ }^{(6)}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \Omega, \mathrm{C}_{\mathrm{L}}=0.1 \mu \mathrm{~F}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 110 |  | $\mu \mathrm{s}$ |
| $t_{R}$ | Vout Rise Time ${ }^{(6)}$ |  |  | 110 |  |  |
| ton | Turn-On Time ${ }^{(6)}$ |  |  | 220 |  |  |
| $t_{\text {DofF }}$ | Turn-Off Delay ${ }^{(6)}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \Omega, \mathrm{C}_{\mathrm{L}}=0.1 \mu \mathrm{~F}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{FPF} 1207 \end{aligned}$ |  | 7 |  | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{F}}$ | Vout Fall Time ${ }^{(6)}$ |  |  | 2 |  |  |
| $\mathrm{t}_{\text {OFF }}$ | Turn-Off Time ${ }^{(6)}$ |  |  | 9 |  |  |
| $\mathrm{t}_{\text {DOFF }}$ | Turn-Off Delay | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \Omega, \mathrm{C}_{\mathrm{L}}=0.1 \mu \mathrm{~F}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{FPF} 1208 \end{aligned}$ |  | 2.0 |  | $\mu \mathrm{s}$ |
| $t_{\text {F }}$ | Vout Fall Time |  |  | 1.9 |  |  |
| toff | Turn-Off Time |  |  | 3.9 |  |  |
| $\mathrm{t}_{\text {DOFF }}$ | Turn-Off Delay | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=500 \Omega, \mathrm{C}_{\mathrm{L}}=0.1 \mu \mathrm{~F}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{FPF} 1207 \end{aligned}$ |  | 10 |  | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{F}}$ | $V_{\text {out }}$ Fall Time |  |  | 95 |  |  |
| toff | Turn-Off Time ${ }^{(6)}$ |  |  | 105 |  |  |
| $t_{\text {DOFF }}$ | Turn-Off Delay | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=500 \Omega, \mathrm{C}_{\mathrm{L}}=0.1 \mu \mathrm{~F}, \\ & \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{FPF} 1208^{(7)} \end{aligned}$ |  | 7.0 |  | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{F}}$ | Vout Fall Time |  |  | 10.5 |  |  |
| toff | Turn-Off Time ${ }^{(6)}$ |  |  | 17.5 |  |  |

## Notes:

5. These parameters are guaranteed by design and characterization; not production tested.
6. $t_{\text {DON }} / t_{\text {DOFF }} / t_{R} / t_{F}$ are defined in Figure 25.
7. Output discharge path is enabled during device off.

## Typical Performance Characteristics



Figure 7. Shutdown Current vs. Temperature


Figure 9. Off Supply Current vs. Temperature (FPF1207, Vout Floating)


Figure 11. Quiescent Current vs. Temperature


Figure 8. Shutdown Current vs. Supply Voltage


Figure 10. Off Supply Current vs. Supply Voltage (FPF1207, V VUt Floating)


Figure 12. Quiescent Current vs. Supply Voltage

## Typical Performance Characteristics



Figure 13. Ron vs. Temperature


Figure 15. ON-Pin Threshold vs. VIN


Figure 14. Ron vs. Supply Voltage


Figure 16. V ${ }_{\text {out }}$ Rise and Fall Time vs. Temperature at $R_{L}=10 \Omega$


Figure 17. V оut Turn-On and Turn-Off Delay vs. Temperature at $\mathrm{R}_{\mathrm{L}}=10 \Omega$

## Typical Performance Characteristics



Figure 18. Vout Rise and Fall Time vs. Temperature at $\mathrm{R}_{\mathrm{L}}=500 \Omega$


Figure 20. Turn-On Response ( $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{C}_{\mathrm{IN}}=1 \mu \mathrm{~F}$, $C_{\text {OUT }}=0.1 \mu \mathrm{~F}, \mathrm{R}_{\mathrm{L}}=10 \Omega$ )


Figure 22. Turn-Off Response (FPF1207 = No Output Pull-Down Resistor)
( $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{C}_{\mathrm{IN}}=1 \mu \mathrm{~F}, \mathrm{C}_{\text {OUT }}=0.1 \mu \mathrm{~F}, \mathrm{R}_{\mathrm{L}}=500 \Omega$ )

## Typical Performance Characteristics



Figure 23. Isw vs. V ${ }_{\text {DS }}$-- SOA of FPF1207


Figure 24. Isw vs. V ${ }_{\text {DS }}$-- SOA of FPF1208

## Timing Diagram



Figure 25. Timing Diagram

## Notes:

8. $t_{\mathrm{O}}=\mathrm{t}_{\mathrm{R}}+\mathrm{t}_{\text {DON }}$.
9. $\mathrm{t}_{\mathrm{OFF}}=\mathrm{t}_{\mathrm{F}}+\mathrm{t}_{\text {DOFF }}$.

## Operation and Application Description

The FPF1207 and FPF1208 are low-Ron P-channel load switches with controlled turn-on. The core of each device is a $50 \mathrm{~m} \Omega$ P-channel MOSFET and controller capable of functioning over a wide input operating range of $1.2-4.0 \mathrm{~V}$. The ON pin, an active HIGH GIOP/CMOScompatible input, controls the state of the switch.

The FPF1208 contains a $65 \Omega$ on-chip load resistor for quick output discharge when the switch is turned off.

## Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor or short-circuit, a capacitor must be placed between the $\mathrm{V}_{\mathbb{I N}}$ and GND pins. A $1 \mu \mathrm{~F}$ ceramic capacitor, $\mathrm{C}_{\mathrm{IN}}$, placed close to the pins is usually sufficient. Higher-value $\mathrm{C}_{\mathrm{IN}}$ can be used to reduce the voltage drop in higher-current applications.

## Output Capacitor

A $0.1 \mu \mathrm{~F}$ capacitor, $\mathrm{C}_{\text {out, }}$, should be placed between the $V_{\text {OUt }}$ and GND pins. This capacitor prevents parasitic
board inductance from forcing $\mathrm{V}_{\text {OUt }}$ below GND when the switch is on. $\mathrm{C}_{\mathrm{IN}}$ greater than $\mathrm{C}_{\text {OUt }}$ is highly recommended. $\mathrm{C}_{\text {out }}$ greater than $\mathrm{C}_{\mathrm{IN}}$ can cause $\mathrm{V}_{\text {OUt }}$ to exceed $\mathrm{V}_{\mathrm{IN}}$ when the system supply is removed. This could result in current flow through the body diode from Vout to Vin.

## Board Layout

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effect that parasitic trace inductance may have on normal and short-circuit operation. Using wide traces or large copper planes for all pins ( $\mathrm{V}_{\text {IN }}, \mathrm{V}_{\text {out }}, \mathrm{ON}$, and GND) helps minimize the parasitic electrical effects along with minimizing the case ambient thermal impedance. However, the Vout pin of FPF1208 should not connect directly the battery source due to the discharge mechanism of the load switch.

Figure 26. Typical Application

## Physical Dimensions



## NOTES:

A. NO JEDEC REGISTRATION APPLIES.
B. DIMENSIONS ARE IN MILLIMETERS.
C. DIMENSIONS AND TOLERANCE PER ASME Y14.5M, 1994.
D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
E. PACKAGE NOMINAL HEIGHT IS 500 MICRONS $\pm 39$ MICRONS (461-539 MICRONS).
F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.
G. DRAWING FILNAME: MKT-UC004AFrev1.

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